

#### 1. Global joint venture starts operations as WeEn Semiconductors

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Thank you for your cooperation and understanding,

WeEn Semiconductors



**Product data sheet** 

## 1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT78 (TO-220AB) plastic package intended for use in applications requiring good bidirectional blocking voltage capability, high surge current capability, high junction temperature capability and high thermal cycling performance.

#### 2. Features and benefits

- Good bidirectional blocking voltage capability
- High junction operating temperature capability
- High surge current capability
- High thermal cycling performance
- Planar passivated for voltage ruggedness and reliability

### 3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

#### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DRM</sub>	repetitive peak off- state voltage		-	-	500	V
$V_{RRM}$	repetitive peak reverse voltage		-	-	500	V
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	-	-	132	Α
		half sine wave; $T_{j(init)} = 25 ^{\circ}\text{C}$ ; $t_p = 10  \text{ms}$ ; Fig. 4; Fig. 5	-	-	120	А
T <sub>j</sub>	junction temperature		-	-	150	°C
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; $T_{mb} \le 133 ^{\circ}\text{C}$ ; Fig. 1; Fig. 2; Fig. 3	-	-	12.5	А





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Symbol Parameter Conditions		Min	Тур	Max	Unit	
Static characte	eristics					
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 ^{\circ}\text{C}; Fig. 6$	-	2	15	mA

# 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	mb	А <del>-     -</del> К
2	Α	anode	704	G sym037
3	G	gate		ŕ
mb	A	mounting base; connected to anode		
			TO-220AB (SOT78)	

# 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BT151-500RT	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

# 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	ı	Min	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage			-	500	V
V <sub>RRM</sub>	repetitive peak reverse voltage			-	500	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>mb</sub> ≤ 133 °C		-	8	Α
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; $T_{mb} \le 133 ^{\circ}\text{C}$ ; Fig. 2; Fig. 3	-	-	12.5	Α
I <sub>TSM</sub>	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25 ^{\circ}C$ ; $t_p = 8.3  \text{ms}$		-	132	Α
		half sine wave; $T_{j(init)} = 25 ^{\circ}C$ ; $t_p = 10  \text{ms}$ ; Fig. 4; Fig. 5		-	120	A

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Symbol	Parameter	Conditions	Min	Max	Unit
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN	-	72	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state current	$I_T$ = 20 A; $I_G$ = 50 mA; $dI_G/dt$ = 50 mA/ $\mu s$	-	50	A/µs
I <sub>GM</sub>	peak gate current		-	4	Α
$V_{RGM}$	peak reverse gate voltage		-	5	V
P <sub>GM</sub>	peak gate power		-	5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	1	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

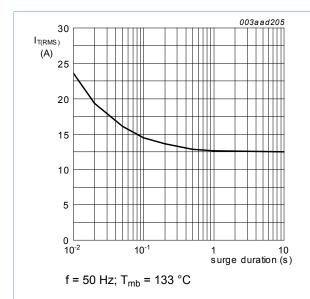


Fig. 1. RMS on-state current as a function of surge duration; maximum values

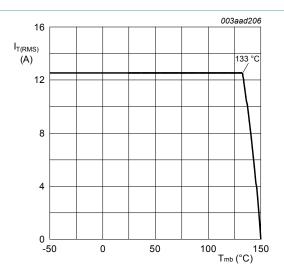


Fig. 2. RMS on-state current as a function of mounting base temperature; maximum values

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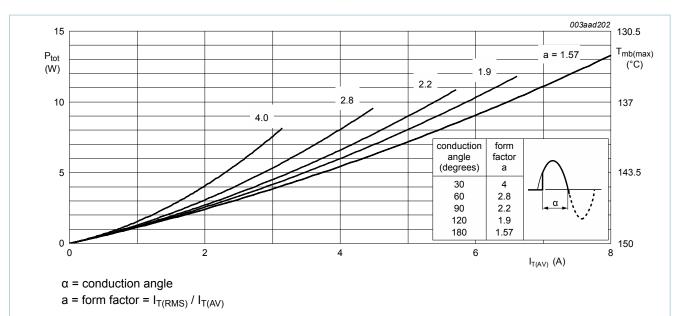


Fig. 3. Total power dissipation as a function of average on-state current; maximum values

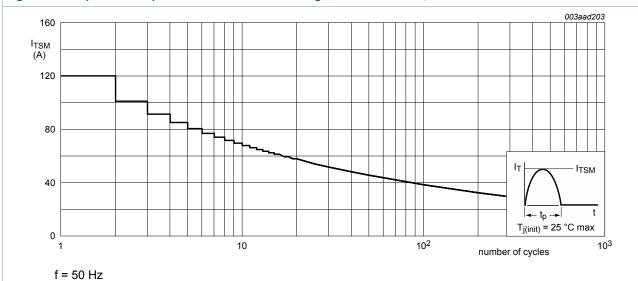
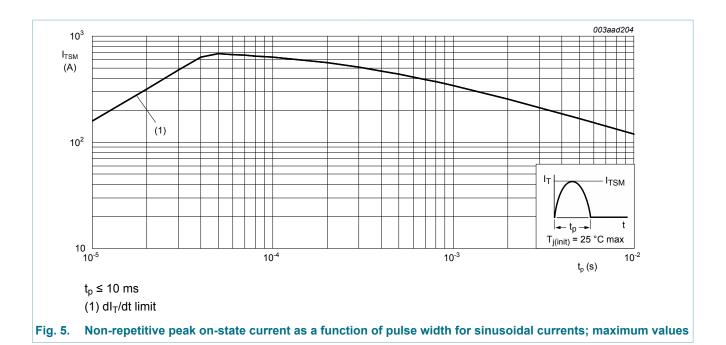


Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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### 8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	-	60	_	K/W

#### 9. Characteristics

Table 6. Characteristics

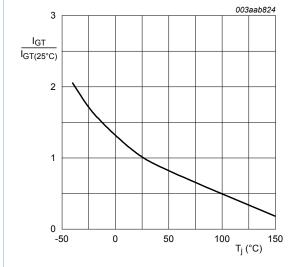
Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
Static chara	Static characteristics								
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 ^{\circ}\text{C}; Fig. 6$		-	2	15	mA		
IL	latching current	$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T_j = 25 \text{ °C}; Fig. 7$		-	10	40	mA		
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>		-	7	20	mA		
$V_{T}$	on-state voltage	I <sub>T</sub> = 23 A; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>		-	1.4	1.75	V		
$V_{GT}$	gate trigger voltage	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C};$ Fig. 10		-	0.6	1	V		
		$V_D = 500 \text{ V}; I_T = 0.1 \text{ A}; T_j = 150 °C;$ Fig. 10		0.25	0.4	-	V		
I <sub>D</sub>	off-state current	V <sub>D</sub> = 500 V; T <sub>j</sub> = 150 °C		-	0.5	2.5	mA		
I <sub>R</sub>	reverse current	V <sub>R</sub> = 500 V; T <sub>j</sub> = 150 °C		-	0.5	2.5	mA		

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic ch	naracteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 335 V; $T_j$ = 150 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); gate open circuit; exponential waveform; Fig. 11	-	300	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM}$ = 40 A; $V_D$ = 500 V; $I_G$ = 0.1 A; $dI_G/dt$ = 5 A/µs; $T_j$ = 25 °C	-	2	-	μs
tq	commutated turn-off time	$V_{DM}$ = 335 V; $T_j$ = 150 °C; $I_{TM}$ = 20 A; $V_R$ = 25 V; $(dI_T/dt)_M$ = 30 A/ $\mu$ s; $dV_D/dt$ = 50 V/ $\mu$ s; $R_{GK}$ = 100 $\Omega$ ; $(V_{DM}$ = 67% of $V_{DRM})$	-	70	-	μs



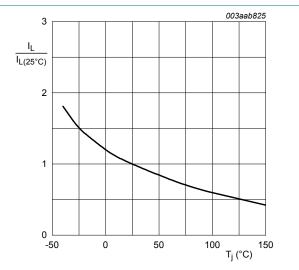


Fig. 6. Normalized gate trigger current as a function of junction temperature

. 7. Normalized latching current as a function of junction temperature

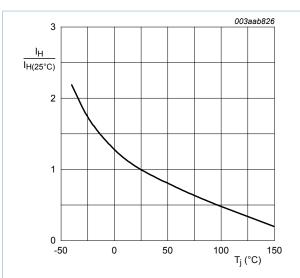
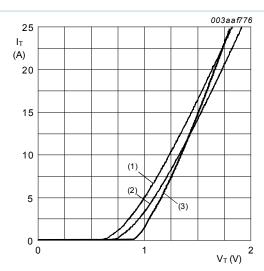


Fig. 8. Normalized holding current as a function of junction temperature



Vo = 0.825 V; Rs = 0.41 Ω

(1) Tj = 150°C; typical values

(2) Tj = 150°C; maximum values

(3) Tj = 25°C; maximum values

Fig. 9. On-state current as a function of on-state voltage

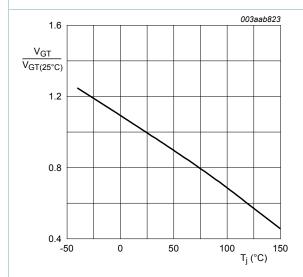
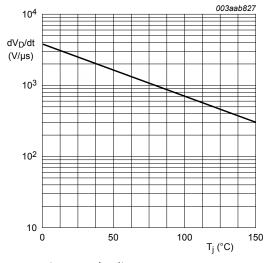


Fig. 10. Normalized gate trigger voltage as a function of junction temperature



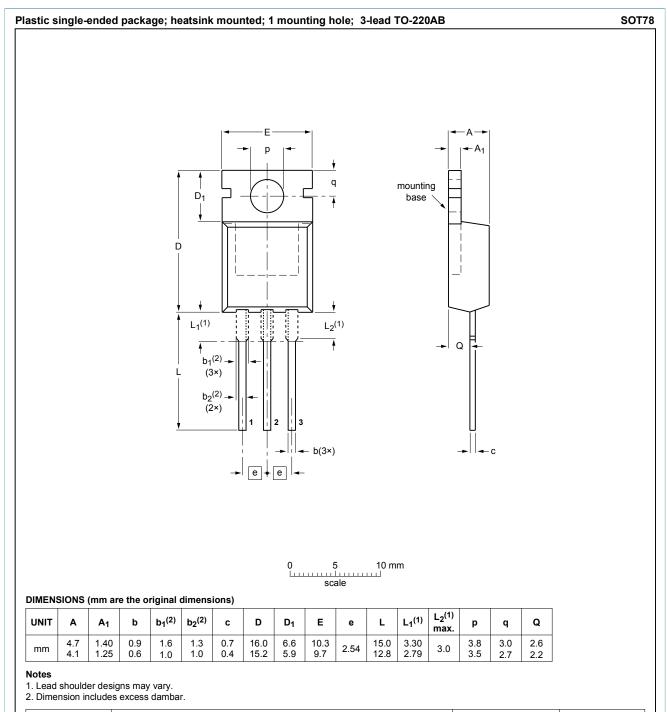
gate open circuit

Fig. 11. Critical rate of rise of off-state voltage as a function of junction temperature; typical values

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# 10. Package outline



OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE
SOT78		3-lead TO-220AB	SC-46			<del>08-04-23</del> 08-06-13

Fig. 12. Package outline TO-220AB (SOT78)

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